

Voltage Variable Absorptive Attenuator
12 dB, DC-2.0 GHz

AT-250
V4

Features

- 12 dB Voltage Variable Attenuation
- Low Intermodulation Products
- Low DC Power Consumption: 50 μ W
- Single Voltage Control: 0 to -4 Volts
- Nanosecond Switching Speed
- Temperature Range: -40°C to +85°C
- SOIC-8 Plastic Package
- Tape and Reel Packaging Available

Description

M/A-COM's AT-250 is a GaAs MMIC voltage variable absorptive attenuator in a low cost SOIC 8-lead surface mount plastic package. The AT-250 is ideally suited for use where attenuation fine tuning, fast switching and very low power consumption are required.

Typical applications include radio, cellular, GPS equipment and other automatic gain/level control circuits.

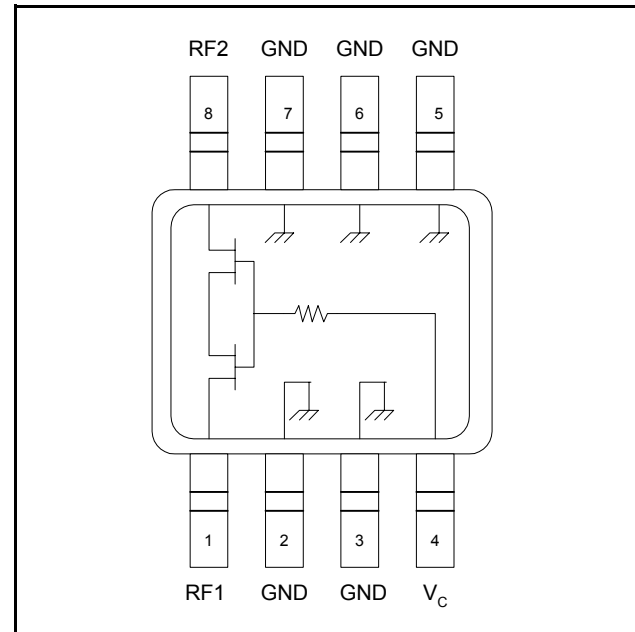
The AT-250 is fabricated with a monolithic GaAs MMIC using a mature 1-micron process. The process features full chip passivation for increased performance and reliability.

Ordering Information

| Part Number | Package |
|-------------|-----------------------------|
| AT-250 | SOIC 8-Lead Plastic Package |
| AT-250TR | Forward Tape and Reel |

Note: Reference Application Note M513 for reel size information.

Functional Schematic



Pin Configuration

| Pin No. | Function | Pin No. | Function |
|---------|----------------|---------|----------|
| 1 | RF1 | 5 | Ground |
| 2 | Ground | 6 | Ground |
| 3 | Ground | 7 | Ground |
| 4 | V _c | 8 | RF2 |

Absolute Maximum Ratings ¹

| Parameter | Absolute Maximum |
|-----------------------|------------------|
| Input Power | +21 dBm |
| Control Voltage | +5V, -8.5V |
| Operating Temperature | -40°C to +85°C |
| Storing Temperature | -65°C to +150°C |

1. Exceeding any one or combination of these limits may cause permanent damage to this device.

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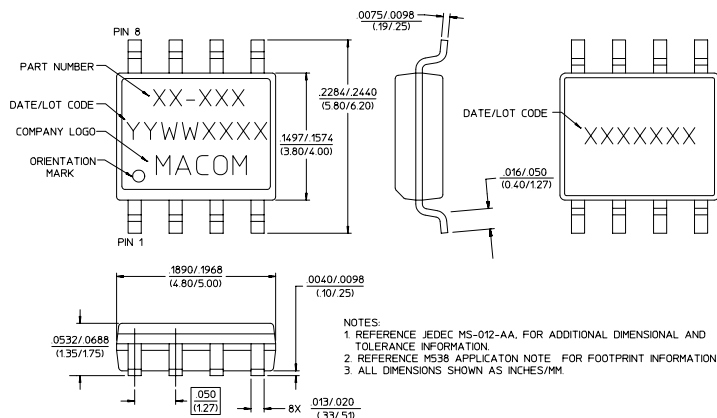
Electrical Specifications: $T_A = 25^\circ\text{C}$, $Z_0 = 50 \Omega$

| Parameter | Test Conditions ² | Units | Min | Typ | Max |
|----------------------------|--|-------|------|-----------------|-----------|
| Insertion Loss | DC - 0.1 GHz | dB | — | 2.9 | 3.1 |
| | DC - 0.5 GHz | dB | — | 3.0 | 3.2 |
| | DC - 1.0 GHz | dB | — | 3.2 | 3.5 |
| | DC - 2.0 GHz | dB | — | 3.4 | 3.8 |
| Flatness (Peak to Peak) | DC - 0.1 GHz | dB | — | ± 0.1 | ± 0.3 |
| | DC - 0.5 GHz | dB | — | ± 0.2 | ± 0.4 |
| | DC - 1.0 GHz | dB | — | ± 0.5 | ± 0.8 |
| | DC - 2.0 GHz | dB | — | ± 1.2 | ± 1.5 |
| VSWR | | Ratio | — | 2.1:1 | — |
| Trise, Tfall | 10% to 90% RF, 90% to 10% RF | nS | — | 3 | — |
| Ton, Toff | 50% Control to 90% RF, 50% Control to 10% RF | nS | — | 5 | — |
| Transients | In Band | mV | — | 10 | — |
| Power Handling | Linear Operation | dBm | — | 13 | — |
| | Absolute Maximum Input Power | dBm | — | 21 | — |
| IP ₂ | 0.05 GHz | dBm | 28 | 34 | — |
| | 0.5 - 2.0 GHz Measured Relative to Input Power (For two-tone Input Power Up to +5 dBm) | dBm | 40 | 47 | — |
| IP ₃ | 0.05 GHz | dBm | 18 | 31 ³ | — |
| | 0.5 - 2.0 GHz Measured Relative to Input Power (For two-tone Input Power Up to +5 dBm) | dBm | 18.5 | 36 ³ | — |

2. Control voltage: 0 to -4 volts @ 20 μA typical.

3. For levels above 6 dB attenuation. For levels below 6 dB, the minimum specification numbers apply.

SOIC-8

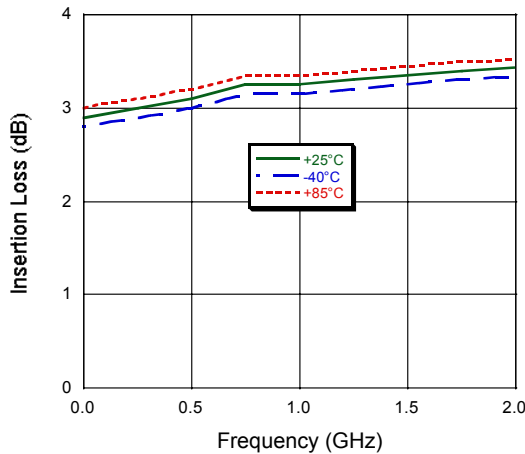


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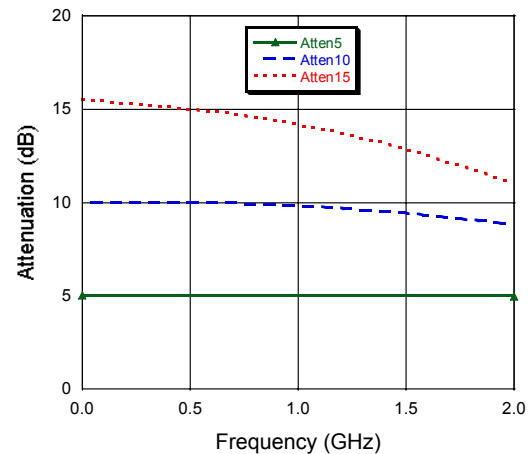
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Typical Performance Curves

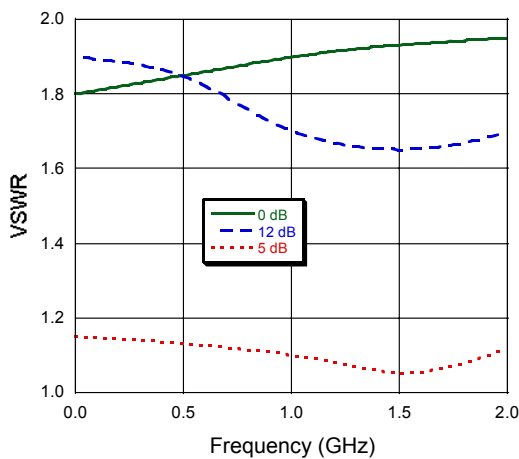
Insertion Loss vs. Frequency



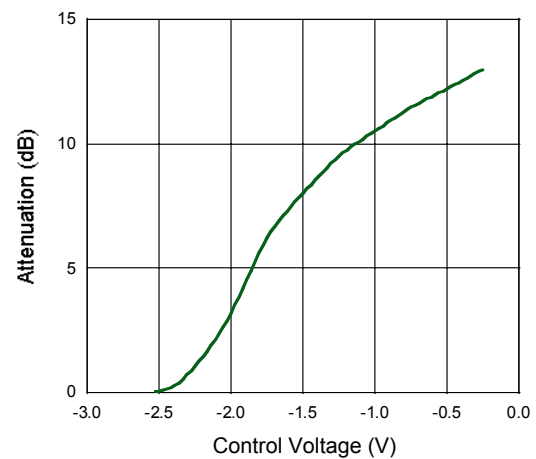
Attenuation vs. Frequency



VSWR vs. Frequency



Attenuation vs. Control Voltage, F = 950 MHz



Phase vs. Control Voltage, F = 950 MHz

